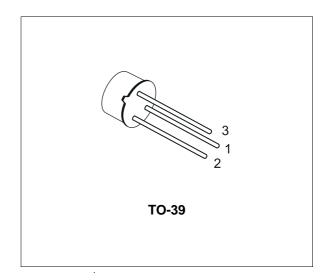


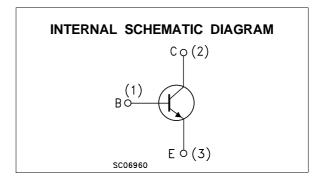
GENERAL PURPOSE TRANSISTOR

DESCRIPTION

The BC141-16 is a silicon Planar Epitaxial NPN transistor in Jedec TO-39 metal case. It is particularly designed for audio amplifiers and switching application up to 1A.

The complementary PNP type is the BC161-16.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage (I _E = 0)	100	V
V_{CEO}	Collector-Emitter Voltage (I _B = 0)	60	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)	7	V
Ic	Collector Current	1	А
I _B	Base Current	0.1	А
P _{tot}	Total Dissipation at T _{amb} ≤ 25 °C	0.65	W
	at T _C ≤ 25 °C	3.7	W
T _{stg}	Storage Temperature	-55 to 175	°C
T _i	Max. Operating Junction Temperature	175	°C

January 2003 1/5

THERMAL DATA

R _{thj-case}	Thermal Resistance Junction-Case		35	°C/W
R _{thj-amb}	Max		200	°C/W
	Thermal Resistance Junction-Ambient	Max		

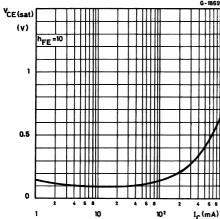
ELECTRICAL CHARACTERISTICS ($T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

Symbol Parameter		Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = 60 V V _{CE} = 60 V T _C = 150 °C			100 100	nΑ μΑ
$V_{(BR)CBO}^*$	Collector-Base Breakdown Voltage (I _E = 0)	I _C = 100 μA	100			V
$V_{(BR)CEO^*}$	Collector-Emitter Breakdown Voltage (I _B = 0)	I _C = 30 mA	60			V
$V_{(BR)EBO}^*$	Emitter-Base Breakdown Voltage (I _C = 0)	I _E = 100 μA	7			V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	$I_{C} = 100 \text{ mA}$ $I_{B} = 10 \text{ mA}$ $I_{C} = 500 \text{ mA}$ $I_{B} = 50 \text{ mA}$ $I_{C} = 1 \text{ A}$ $I_{B} = 100 \text{ mA}$		0.1 0.35 0.6	1	V V V
V _{BE(on)} *	Base-Emitter On Voltage	I _C = 1 A V _{CE} = 1 V		1.25	1.8	V
h _{FE} *	DC Current Gain	I _C = 100 μA	100	90 160 30	250	
f_{T}	Transition Frequency	$I_C = 50 \text{ mA}$ $V_{CE} = 10 \text{ V}$	50			MHz
Ссво	Collector-Base Capacitance	$I_E = 0$ $V_{CB} = 5 V$ $f = 1MHz$		12	25	pF
t_{on}	Turn-on Time	$I_{C} = 100 \text{ mA}$ $I_{B1} = 5 \text{ mA}$			250	ns
t _{off}	Turn-off Time	$I_C = 100 \text{ mA}$ $I_{B1} = I_{B2} = 5 \text{ mA}$			850	ns

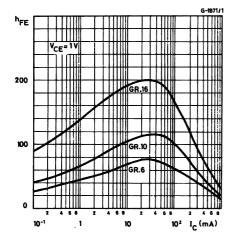
^{*} Pulsed: Pulse duration = 300 μs, duty cycle ≤ 1 %

2/5

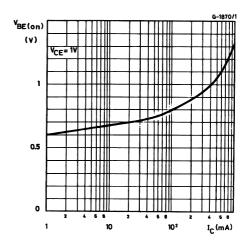
Collector-emitter Saturation Voltage.



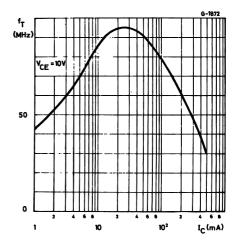
DC Curent Gain.



Base-emitter Voltage.

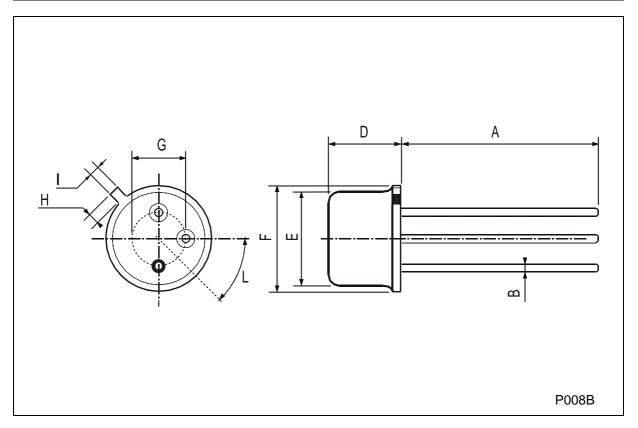


Transiition Frequency.



TO-39 MECHANICAL DATA

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	12.7			0.500		
В			0.49			0.019
D			6.6			0.260
Е			8.5			0.334
F			9.4			0.370
G	5.08			0.200		
Н			1.2			0.047
ı			0.9			0.035
L	45° (typ.)					



4/5

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics

© 2002 STMicroelectronics – Printed in Italy – All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

http://www.st.com



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

STMicroelectronics:

BC141-16